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Fifth Semester B.E. Degree Examination, December 2012
Microwaves and Radar

Time: 3 hrs.

Max. Marks:100

**Note:1. Answer FIVE full questions, selecting
at least TWO questions from each part.
2. Candidates are allowed to use Smith charts.**

PART – A

- 1 a. Define SWR and reflection co-efficient of a microwave transmission line. (06 Marks)
b. The normalized impedance of a microwave transmission line $Z_l = 1 + j1$ and the operating wavelength $\lambda = 5$ cm. Using Smith chart determine the first voltage maxima, first voltage minima from the load. Also find VSWR. (09 Marks)
c. Describe the single stab matcher. (05 Marks)
- 2 a. Derive TM_{mn} mode characteristic equations in rectangular waveguides. (10 Marks)
b. The TE_{10} mode is described as the dominant mode in rectangular waveguides. What property does it have which makes it dominant? (05 Marks)
c. What are cavity resonators? What applications do they have? (05 Marks)
- 3 a. Draw the schematic diagram of an IMPATT diode, and explain its operation. (10 Marks)
b. A typical n-type GaAs Gunndiode has following parameters:
Threshold field $E_{th} = 2800$ V/cm
Applied voltage $E = 3200$ V/cm
Device length $L = 10$ μ m
Doping concentration $n_0 = 2 \times 10^{14}$ cm^{-3}
Operating frequency $f = 10$ GHz
i) Compute the electron drift velocity.
ii) Calculate the current density.
iii) Estimate the negative electron mobility. (06 Marks)
c. Briefly explain the operation of PIN diode. (04 Marks)
- 4 a. What are the advantages of [S] matrices over [Z] matrices? (06 Marks)
b. List the common properties for [S] and [Z] matrices. (04 Marks)
c. Define insertion loss, transmission loss, return loss interms of s-parameters. (10 Marks)

PART – B

- 5 a. With the aid of neat sketch, describe characteristics and s-matrix for Magic – Tee (10 Marks)
b. Justify the statement : “An ideal isolator is a non reciprocal transmission device” (05 Marks)
c. Briefly explain the operation of phase shifter. (05 Marks)
- 6 a. Obtain the attenuation constants for the conductor and dielectric losses of a parallel strip line. (06 Marks)
b. A lossless parallel strip line has a conducting strip width ‘W’. The substrate dielectric separately the two conducting strips has a relative dielectric constant ϵ_{rd} of 6 (Beryllium oxide BeO) and thickness of ‘d’ of 4 mm. Calculate i) The required width W of the conducting strip in order to have a characteristic impedance of 50 Ω . ii) The strip line capacitance. iii) The strip line inductance iv) The phase velocity of the wave in the parallel strip line. (08 Marks)
c. What are the advantages of coplanar strip line over conventional parallel strip line? (06 Marks)

- 7 a. Draw the block diagram of a basic radar set and explain the essential of its operation. **(06 Marks)**
- b. Derive the basic radar range equation, as governed by the minimum receivable echo power P_{\min} . **(10 Marks)**
- c. Calculate the maximum range of a radar system which operates at 3 cm. With peak pulse power of 500 kW, if its minimum receivable power is 10^{-13}W , the capture area of its antenna is 5 m^2 and the radar cross-sectional area of the target is 20 m^2 . **(04 Marks)**
- 8 a. With the aid of a block diagram, explain fully the operation of an MTI radar system using a power amplifier in the transmitter. **(12 Marks)**
- b. What is the Doppler effect? **(04 Marks)**
- c. What are the advantages offered by digital MTI processing? **(04 Marks)**

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